



INFORMATION DISCLOSURE STATEMENT

Applicant : Chetan Singh Solanki
App. No : 10/670,754
Filed : September 24, 2003
For : METHOD AND APPARATUS FOR
CONTINUOUS FORMATION AND
LIFT-OFF OF POROUS SILICON
LAYERS
Examiner : Evan T. Pert
Art Unit : 2829

CERTIFICATE OF MAILING

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first-class mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA, 22313 on

March 8, 2005
(Date)

John M. Carson, Reg. No. 34,303

Mail Stop Amendment
 Commissioner for Patents
 P.O. Box 1450
 Alexandria, VA 22313-1450

Dear Sir:

Enclosed for filing in the above-identified application is an Information Disclosure Statement by Applicant (PTO/SB/08 equivalent) listing five (5) references to be considered by the Examiner. Also enclosed are five (5) copies of foreign patent references and/or non-patent literature as listed on the Information Disclosure Statement.

This Information Disclosure Statement is being filed before the mailing date of a final action and before the mailing of a Notice of Allowance. This Statement is accompanied by the fees set forth in 37 C.F.R. § 1.17(p). The Commissioner is hereby authorized to charge any additional fees which may be required or to credit any overpayment to Account No. 11-1410.

03/15/2005-SPELEKE1 00000023-10675754
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 02-FC:1806

Dated: 3/8/05

Respectfully submitted,
KNOBBE, MARTENS, OLSON & BEAR, LLP

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Multiple sheets used when necessary)</i>	Application No.	10/670,754
	Filing Date	September 24, 2003
	First Named Inventor	Chetan Singh Solanki
	Art Unit	2829
	Examiner	Evan T. Pert
SHEET 1 OF 1	Attorney Docket No.	IMEC197.001CP1

U.S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS						
Examiner Initials	Cite No.	Foreign Patent Document Country Code-Number-Kind Code Example: JP 1234567 A1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear	T ¹

NON PATENT LITERATURE DOCUMENTS

NON-PATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
	1	SOLANKI, et al., Effect of the composition of electrolyte on separation of porous silicon film by electrochemical etching, Phys. Stat. Sol. (a) 197 (2), pgs. 507-511, May 26, 2003, Wiley-VCH Verlag GmbH & Co., KGaA, Weinheim	
	2	BILYALOV, et al., Role of hydrogen in the separation of a porous Si layer in a layer transfer process, Phys. Stat. Sol., (a) 197 (1), pgs. 128-131, April 29, 2003, Wiley-VCH Verlag GmbH & Co., KGaA, Weinheim	
	3	SOLANKI, et al., Development of solar cell processes for free-standing thin silicon films, Physics of Semiconductor Devices, pgs. 1145-1147, 2004 Narosa Publishing House, New Delhi, India	
	4	SOLANKI, et al., Transfer of a thin silicon film on to a ceramic substrate, Thin Solid Films 403-404, pgs. 34-38, 2002 Elsevier Science B.V.	
	5	SOLANKI, et al., Free-Standing Thin-Film Monocrystalline Silicon (FMS) Solar Cells, PV in Europe-From PV Technology to Energy Solutions, pgs. 387-392, October 7-11, 2002, Rome, Italy	

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***Examiner:** Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

T¹ - Place a check mark in this area when an English language Translation is attached.